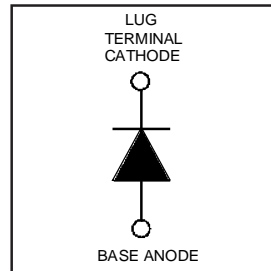


# HFA135NH40R

Ultrafast, Soft Recovery Diode

## Features

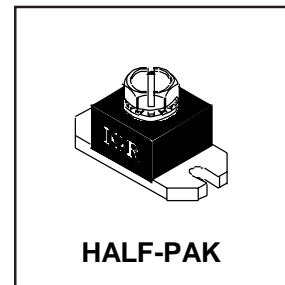
- Reduced RFI and EMI
- Reduced Snubbing
- Extensive Characterization of Recovery Parameters



$V_R = 400V$   
 $V_F(\text{typ.})^{\textcircled{3}} = 1V$   
 $I_F(\text{AV}) = 135A$   
 $Q_{rr}(\text{typ.}) = 290nC$   
 $I_{RRM}(\text{typ.}) = 7.5A$   
 $t_{rr}(\text{typ.}) = 50ns$   
 $di_{(rec)}/dt(\text{typ.})^{\textcircled{3}} = 270A/\mu s$

## Description

HEXFRED™ diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. An extensive characterization of the recovery behavior for different values of current, temperature and di/dt simplifies the calculations of losses in the operating conditions. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for power converters, motors drives and other applications where switching losses are significant portion of the total losses.



## Absolute Maximum Ratings (per Leg)

	Parameter	Max.	Units
$V_R$	Cathode-to-Anode Voltage	400	V
$I_F @ T_C = 25^\circ C$	Continuous Forward Current	211	A
$I_F @ T_C = 100^\circ C$	Continuous Forward Current	103	
$I_{FSM}$	Single Pulse Forward Current <sup>①</sup>	900	
$E_{AS}$	Non-Repetitive Avalanche Energy <sup>②</sup>	1.4	mJ
$P_D @ T_C = 25^\circ C$	Maximum Power Dissipation	379	W
$P_D @ T_C = 100^\circ C$	Maximum Power Dissipation	152	
$T_J$ $T_{STG}$	Operating Junction and Storage Temperature Range	-55 to +150	°C

## Thermal - Mechanical Characteristics

	Parameter	Min.	Typ.	Max.	Units
$R_{thJC}$	Junction-to-Case	—	—	0.33	°C/W
$R_{thCS}$	Case-to-Sink, Flat, Greased Surface	—	0.15	—	K/W
Wt	Weight	—	26 (0.9)	—	g (oz)
	Mounting Torque <sup>④</sup>	15 (1.7)	—	25 (2.8)	lbf•in
	Terminal Torque	30 (3.4)	—	40 (4.6)	(N•m)
	Vertical Pull	—	—	80	lbf•in
	2 inch Lever Pull	—	—	40	

**Note:** <sup>①</sup> Limited by junction temperature  
<sup>②</sup> L = 100µH, duty cycle limited by max  $T_J$   
<sup>③</sup> 125°C

<sup>④</sup> Mounting surface must be smooth, flat, free of burrs or other protrusions. Apply a thin even film of thermal grease to mounting surface. Gradually tighten each mounting bolt in 5-10 lbf•in steps until desired or maximum torque limits are reached. Module

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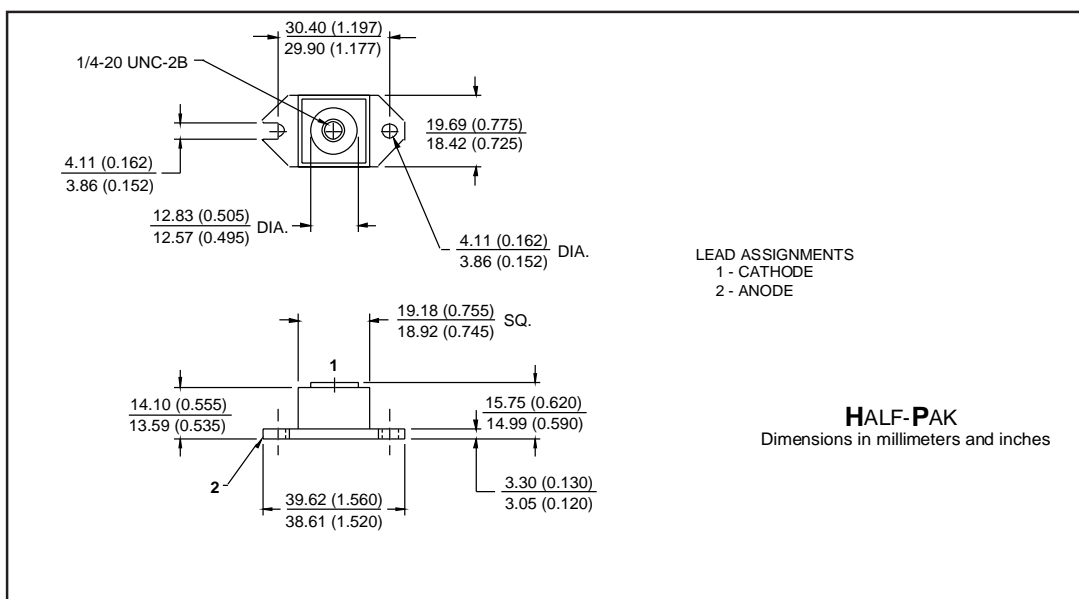
International  
**IOR** Rectifier

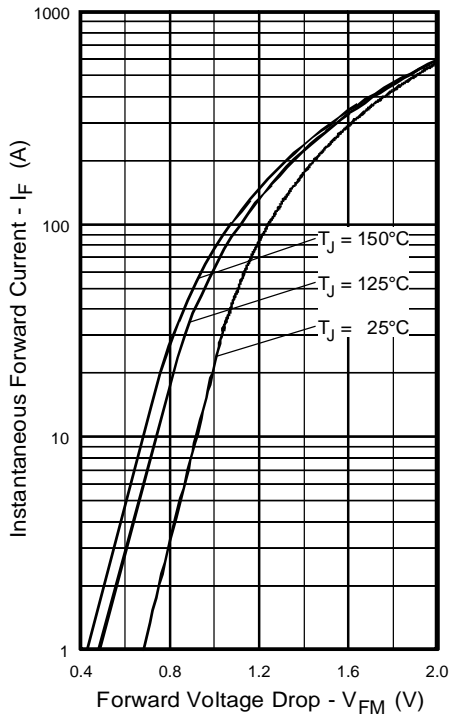
## Electrical Characteristics (per Leg) @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

Parameter	Min.	Typ.	Max.	Units	Test Conditions
$V_{BR}$ Cathode Anode Breakdown Voltage	400	—	—	V	$I_R = 100\mu\text{A}$
$V_{FM}$ Max Forward Voltage See Fig. 1	—	1.1	1.3	V	$I_F = 135\text{A}$
	—	1.4	1.6		$I_F = 270\text{A}$
	—	1.0	1.2		$I_F = 135\text{A}, T_J = 125^\circ\text{C}$
$I_{RM}$ Max Reverse Leakage Current See Fig. 2	—	1.5	9.0	$\mu\text{A}$	$V_R = V_R$ Rated
	—	2.3	12	$\text{mA}$	$T_J = 125^\circ\text{C}, V_R = 320\text{V}$
$C_T$ Junction Capacitance See Fig. 3	—	280	380	$\text{pF}$	$V_R = 200\text{V}$
$L_S$ Series Inductance	—	6.0	—	$\text{nH}$	From top of terminal hole to mounting plane

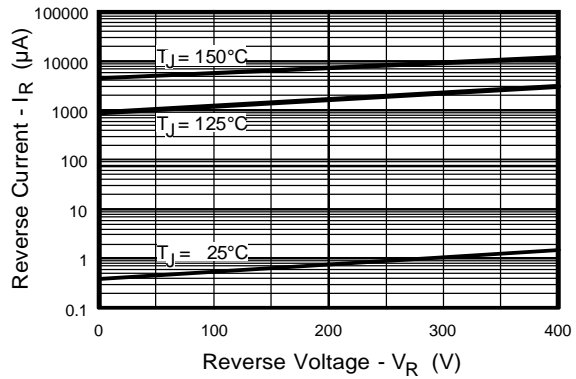
## Dynamic Recovery Characteristics (per Leg) @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

Parameter	Min.	Typ.	Max.	Units	Test Conditions	
$t_{rr}$ Reverse Recovery Time	—	50	—	ns	$I_F = 1.0\text{A}, di_f/dt = 200\text{A}/\mu\text{s}, V_R = 30\text{V}$	
$t_{rr1}$ See Fig. 5	—	77	120			$T_J = 25^\circ\text{C}$
$t_{rr2}$	—	290	440			$T_J = 125^\circ\text{C}$
$I_{RRM1}$ Peak Recovery Current	—	7.5	14	A	$T_J = 25^\circ\text{C}$	
$I_{RRM2}$ See Fig. 6	—	16	30			$T_J = 125^\circ\text{C}$
$Q_{rr1}$ Reverse Recovery Charge	—	290	780	nC	$T_J = 25^\circ\text{C}$	
$Q_{rr2}$ See Fig. 7	—	2300	6300			$T_J = 125^\circ\text{C}$
$di_{(rec)M}/dt1$ Peak Rate of Fall of Recovery Current	—	320	—	$\text{A}/\mu\text{s}$	$T_J = 25^\circ\text{C}$	
$di_{(rec)M}/dt2$ During $t_b$ See Fig. 8	—	270	—			$T_J = 125^\circ\text{C}$

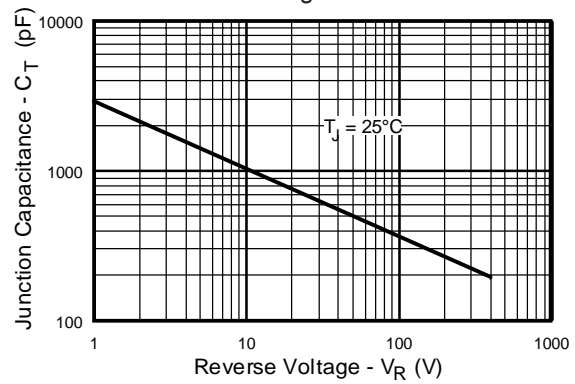




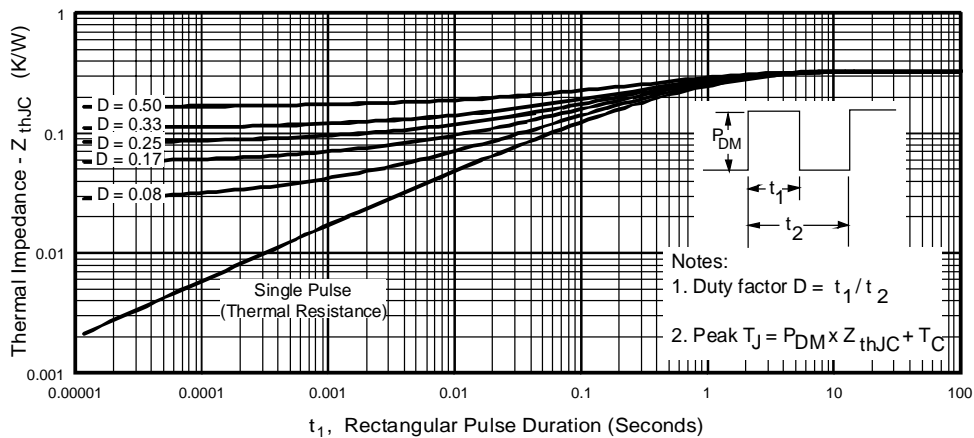
**Fig. 1** - Maximum Forward Voltage Drop vs. Instantaneous Forward Current



**Fig. 2** - Typical Reverse Current vs. Reverse Voltage



**Fig. 3** - Typical Junction Capacitance vs. Reverse Voltage



**Fig. 4** - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

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IOR Rectifier

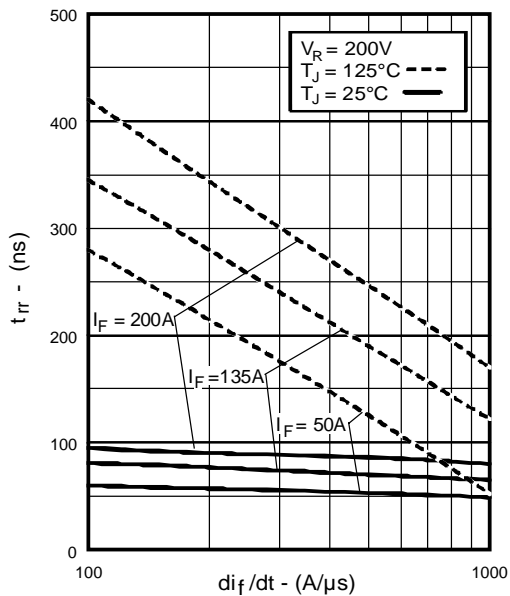


Fig. 5 - Typical Reverse Recovery vs.  $di_f/dt$

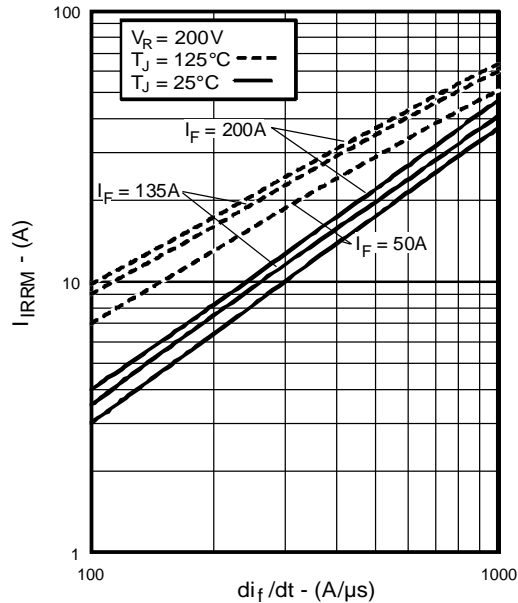


Fig. 6 - Typical Recovery Current vs.  $di_f/dt$

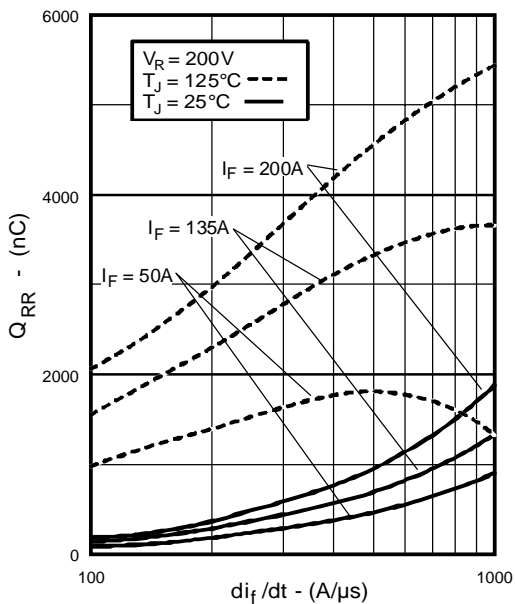


Fig. 7 - Typical Stored Charge vs.  $di_f/dt$

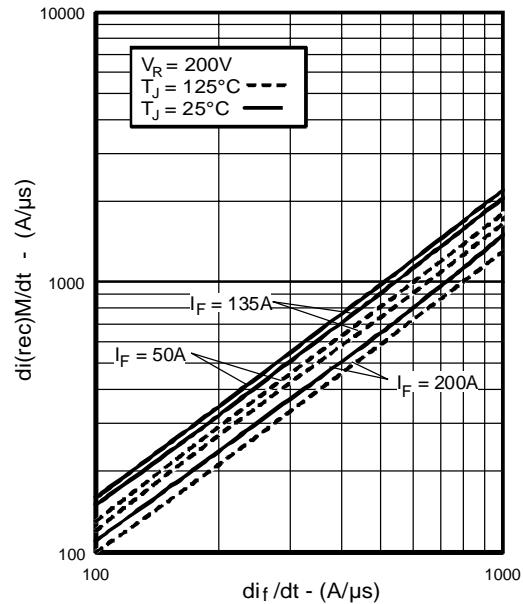
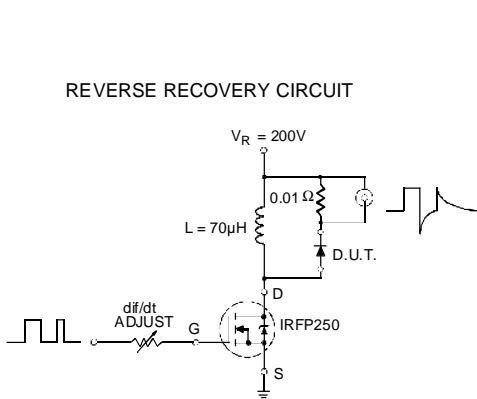
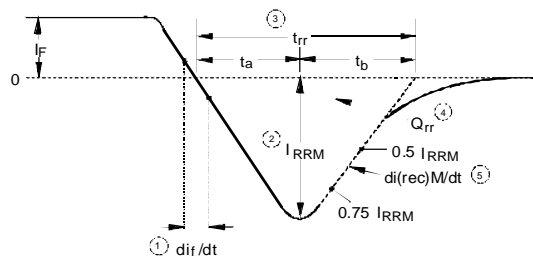


Fig. 8 - Typical  $di_{(rec)M}/dt$  vs.  $di_f/dt$

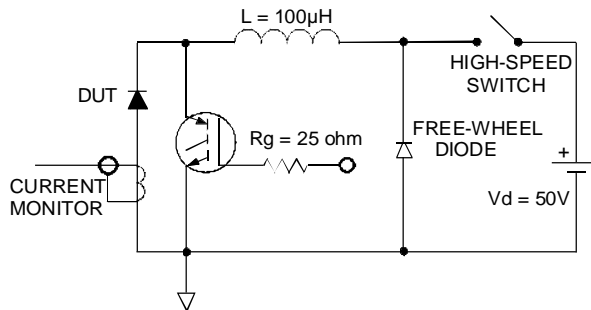


**Fig. 9 - Reverse Recovery Parameter Test Circuit**



1.  $di/dt$  - Rate of change of current through zero crossing
  2.  $I_{RRM}$  - Peak reverse recovery current
  3.  $t_{rr}$  - Reverse recovery time measured from zero crossing point of negative going  $I_F$  to point where a line passing through  $0.75 I_{RRM}$  and  $0.50 I_{RRM}$  extrapolated to zero current
  4.  $Q_{rr}$  - Area under curve defined by  $t_{rr}$  and  $I_{RRM}$
  5.  $di_{(rec)}/dt$  - Peak rate of change of current during  $t_b$  portion of  $t_{rr}$
- $$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

**Fig. 10 - Reverse Recovery Waveform and Definitions**



**Fig. 11 - Avalanche Test Circuit and Waveforms**